

DFT and kinetics study of O/O₂ mixtures reacting over a graphite (0001) basal surface

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Abstract

Spin-polarised density functional calculations were used to investigate the interaction of atomic and molecular oxygen on the basal graphite surface at several atomic coverages. Two carbon layers were enough to represent the graphite surface. Oxygen atoms bind mainly over C-C bridge sites forming an epoxide-like structure with a two carbon puckering and with adsorption energies in the 0.95-1.28 eV range, depending on the atomic coverage. Molecular oxygen only shows a very weak physisorption. Atomic adsorption and diffusion along with atomic recombination via Eley-Rideal and Langmuir-Hinshelwood mechanisms were studied. All surface processes were activated with energy barriers that decreased for lower atomic coverages. Relaxation effects were non-negligible. A microkinetic model with six elementary surface processes was proposed to see the overall behavior of several initial O/O₂ mixtures flowing over a graphite surface at 300-1000 K. Thermal rate constants were derived from Density Functional Theory (DFT) data and standard Transition State Theory. A very low steady-state atomic coverage ($\theta_O < 0.5 \%$) was predicted and also very low atomic recombination coefficients were observed ($\gamma_O < 5 \times 10^{-4}$). The Eley-Rideal together with the adsorption and desorption processes were much more important than the Langmuir-Hinshelwood reaction.

Keywords Adsorption, Diffusion, Atomic recombination, Oxygen, Graphite, Microkinetic model

Tables: 5
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1 Introduction

Carbon-based materials have received considerable attention for their use in spacecraft components (e.g., reinforced C is used as a thermal protection system (TPS) in the nose of Space Shuttle) due to their light weight and high strength. In the low Earth orbits (LEO), 160-2000 km above Earth's surface, atomic oxygen is one of the main present species and can collide with the spacecraft surface at very high translational energies (i.e., about 4.5 ± 1.0 eV due to the orbital velocity of around 7.5 km/s) producing an important etching, hence degrading any C-based TPS [1]. Moreover, during hypersonic reentry flights into Earth's atmosphere (e.g., Space Shuttle) not only atomic oxygen but also molecular oxygen processes can be relevant to understand properly the huge heat transfer and the TPS behavior under these extreme conditions [2]. Therefore, a good understanding of all elementary processes involving atomic and molecular oxygen with carbon-based materials is essential for space technology. Thus, in principle, several heterogeneous processes could compete: a) O adsorption, b) O₂ dissociative or non-dissociative adsorption, c) O recombination via an Eley-Rideal (ER) mechanism (i.e., $O_{(g)} + O_{ad} \rightarrow O_{2(g)}$), d) O recombination via a Langmuir-Hinshelwood (LH) mechanism (i.e., $O_{ad} + O_{ad} \rightarrow O_{2(g)}$) and e) C etching producing CO or CO₂, where *ad* labels adsorbed species and *g* gas species. Another less important elementary processes could also be added.

There are abundant theoretical studies about the interaction of atomic and molecular oxygen with graphite [3-7], graphene [8-9] and carbon nanotubes [4,10-11] covering different aspects but without giving a global approach about the O/O₂ reactivity over these carbon surfaces. They are mainly concerned with adsorption studies over several type of surfaces (e.g., basal, zig-zag, armchair,..) for different coverages. Thus, there was shown that atomic oxygen becomes mainly chemically adsorbed on a bridge position between two adjacent C atoms of graphite or graphene, forming an epoxy group, with adsorption energies in the range of 1.5-3.2 eV for a basal graphite surface depending of the oxygen coverages and the level of the calculations [3-6]. The molecular oxygen seems to be only physically adsorbed on basal graphite surfaces with low adsorption energies of about 0.12 ± 0.01 eV at 1 ML coverage as it has been shown using thermal desorption spectroscopy on highly oriented pyrolytic graphite (HOPG) [12]. Common Density Functional Theory (DFT) studies are not accurate enough to provide reliable adsorption energies for O₂ over graphite [3, 4, 7], due to the importance of the missing van der Waals (vdW) contributions. Nevertheless, a suitable vdW treatment could be done for instance by adding pairwise interatomic C_6R^{-6} terms, where C_6 coefficients can be derived from ground-state electron density for molecules and solids [13]. The inclusion of vdW interactions reproduce quite well the O₂ physisorption over

graphite [14-15]. The interaction of O₂ with defective edge sites on graphite surfaces presents high adsorption energies (2.6-6.2 eV [7]) in a similar way as for atomic oxygen (4.5-5.7 eV [6]). Moreover, molecular oxygen reactively adsorbs on edge graphite surfaces at 300 °C and 1 atm pressure (the perfect basal surface is hardly active [16]), being the energy barrier for O₂ dissociation larger and for CO formation lower when the oxygen surface coverage diminishes [17].

Up to our knowledge there are not theoretical studies about the ER and LH atomic reactions or on the atomic diffusion over graphite surfaces. Characterization of these reaction pathways is missing and it is very important from a kinetic point of view. Only very recently, the migration (diffusion) barrier for O on a graphene sheet has been investigated [8], indicating an energy barrier of 0.58 eV at a coverage of 16.7 %, which would imply a noticeable mobility of isolated adsorbed atoms.

Apart from the mentioned experimental studies about O₂ adsorption/desorption on graphite, there are as well a large number of experimental works concerned mainly with the interaction of hyperthermal atomic oxygen on HOPG surfaces, to understand the erosion and degradation of these surfaces under large collision energies [1,18-19], forming CO and CO₂ gas species.

In this work, we study the main elementary processes involving O and O₂ over an initially clean graphite basal surface (0001) at the same DFT level, characterizing not only the minima but also the transition states (TS) for the different processes at several oxygen coverages. These data are used in a proposed microkinetic model based on calculated thermal rate constants derived from Transition State Theory, which allows a kinetic study for different temperatures and total and partial pressures (i.e., several O/O₂ mixtures). We also determine the atomic oxygen recombination coefficient $\gamma_O(T, P)$ ($0 \leq \gamma_O \leq 1$), which is defined as the total probability of atomic oxygen recombination per atomic oxygen surface collision; γ_O values are necessary in standard computer fluid dynamics (CFD) simulations [2] of hypersonic flights aiming to evaluate their aerodynamic heating.

2 Computational details

The periodic DFT calculations presented in the current work have been carried out using the Vienna ab initio simulation package (VASP) code [20-23], which uses plane wave basis set. The calculations are mainly based on the generalized gradient approximation (GGA) functional revised Perdew-Burke-Ernzerhof functional (RPBE) [24]. However, some initial tests were also done with

Perdew-Burke-Ernzerhof (PBE) [25-26] and Perdew-Wang 91 (PW91) [27-28] functionals. The projector-augmented-wave (PAW) technique within the frozen core approximation has been used to describe the electron-core interaction [29-30]. An energy cutoff of 550 eV has been used in the plane-wave expansion after several tests to confirm the energy convergence of the calculations. Integration over the Brillouin zone was performed by using a 14x14x1, 11x11x1 and 6x6x1 k-point meshes by means of the Monkhorst-Pack method [31] for slab calculations using several supercells, 1x1, 2x2 and 3x3, respectively. For bulk calculations a 14x14x4 mesh was used. The atomic positions were partially (e.g., for gas/rigid slab system) or fully relaxed by using a quasi-Newton algorithm until the energy decreased below 10^{-5} eV, which usually corresponded to forces lower than 10^{-2} eV/Å. The energy convergence in the electronic self-consistent cycles was maintained below 10^{-6} eV for all geometrical optimizations and vibrational frequency calculations. The vacuum used in the slab model was around 15 Å, which was large enough to prevent significant interactions between periodic images.

Due to the important role that spin plays in both atomic and molecular oxygen (i.e., triplet in their ground states), all calculations were spin-polarised.

Several adsorption sites have been studied for O and O₂ species (see next section for details). Moreover, we have calculated minimum energy paths for the above-mentioned elemental processes (e.g., ER reaction, atomic diffusion,.) by means of the Nudged Elastic Band method (NEB) [32-33] or using more simple reaction coordinates (e.g., Z_O distance over a C-C bridge site). Once determined the optimal geometry for each stationary point, we have calculated the Hessian matrix and its corresponding harmonic vibrational frequencies (ν_i) to verify if they were true minima or transition states. We have also checked the connection among these stationary points. In general we have fixed the optimized slab geometry, although some calculations with full or partial slab relaxation were also performed. Energy barriers (ΔE^\ddagger) for the elementary processes were mostly computed using the corresponding supermolecule energy, calculated for reactants far enough to give a converged asymptotic energy.

The adsorption energy (E_{ad}) was calculated according to Eq. 1,

$$E_{ad} = (E_X + E_{slab}) - E_{X/slub} \quad (1)$$

where E_X is the energy of an isolated O or O₂ species at their electronic ground state, E_{slab} is the energy for the relaxed clean slab ($E_X + E_{slab}$ calculated as E_{X+slab}), and $E_{X/slub}$ is the energy of the adsorbed-slab system. Therefore, a positive adsorption energy means that this site is more stable

than the X + slab asymptote; on the contrary, a negative adsorption energy corresponds to a less stable one.

The atomic energy (i.e., -2.41648 eV) was calculated with the oxygen atom inside a large broken symmetry box (e.g., 16x18x17 Å³). The optimized O₂ molecule corresponds to an energy of -10.498232 eV, giving place to a dissociation energy (D_e) of 5.66 eV, an equilibrium distance (R_e) of 1.2348 Å and a vibrational frequency (ν_e) of 1556.0 cm⁻¹, which compare reasonable well with the experimental values [34] 5.21 eV, 1.2075 Å and 1580.2 cm⁻¹, for D_e, R_e and ν_e respectively, in spite of the well known problems to describe the dissociation energy of this open shell molecule, which depends both on the functionals and pseudopotentials used [24].

Thermal rate constants are derived from standard Transition State Theory formula, including reactants and transition state zero point vibrational energies [35].

3 Results and discussion

3.1 Bulk graphite properties

Graphite is formed by a layered structure of six-member carbon rings, stacked in an ABAB sequence with a weak interlayer binding compared to the much stronger binding within the layers. The experimental [36] lattice parameters for graphite structure are reported in table 1.

We have calculated the graphite lattice parameters using several functionals (PW91, PBE and RPBE). The value of optimum $a=b$ lattice parameter is similar and close to the experimental value [36], although the optimum c lattice parameter is overestimated in all cases. The usual fail of GGA approximation to predict the c -axis lattice parameter and the small interlayer binding energy is well known, along with the better LDA description of c (table 1); the inclusion of empirical vdW interactions [37] on both GGA and LDA calculations produce as well good calculated interlayer binding energies. On the contrary, GGA gives much better cohesive energies, being the RPBE value (7.516 eV/atom) very close to the experimental value (7.371 eV/atom). The cohesive energy was calculated from the equation,

$$E_{coh} = \frac{1}{N_C} (N_C \cdot E_{C(g)} - E_{bulk(eq)}) \quad (2)$$

where N_C is the number of C atoms in the cell, $E_{C(g)}$ is the energy of C (triplet) atom and $E_{\text{bulk}(eq.)}$ is the energy corresponding to the equilibrium bulk structure with optimum a and experimental c lattice parameters.

Table 1 also presents the isotropic bulk modulus (B_{iso}) and its pressure derivative (B'_{iso}) obtained from volum changes with a constant c/a ratio, with several c values close to the experimental lattice parameter. B_{iso} and B'_{iso} are derived by means of a fit to the calculated pressure-volume data using the third-order Birch-Murnaghan equation of state [39]. The calculated B_{iso} values are very similar and in good agreement with experimental ones, which were derived from the elastic constants of pyrolytic graphite [40,41]. The correct calculation of the usual bulk modulus (B_0) for highly anisotropic materials imply the use of an uniaxial compression [43] instead of an uniform compression, which could produce values an order of magnitude larger than the experimental ones. Hence, the poor description of the c lattice parameter does not allow a proper calculation of B_0 with the present DFT/GGA calculations.

The calculated B'_{iso} are much lower than the experimental values estimated from the initial slopes of elastic constants with pressure at atmospheric pressure and 295 K [40] as shown in table 1.

In general, we conclude that GGA/RPBE calculations give a reasonable good description of bulk graphite properties, although it is necessary to use the experimental c lattice parameter. This will not be a problem for the reliability of the atom or molecule-slab calculations of the next section as it has been also assumed in similar previous studies [6].

3.2 Adsorption and diffusion of oxygen

We have studied the adsorption of atomic oxygen on the basal (0001) graphite surface, with a slab formed by one or two carbon layers. The results are almost identical regardless of the number of layers of the slab model, possibly due to the very weak interlayer interaction. This fact was also verified in previous O and K adsorption studies over graphite [3] by using 1, 2 or 3 layers. Hence that another similar O/graphite studies have simulated the graphite as a single sheet of C atoms [4].

Three high-symmetry different sites have been mainly considered (Fig. 1): on top of a surface C atom, which is either above another C atom (T1) or above an hexagon hollow (T2) from the adjacent plane, and over a bridge between the two nearest-neighbor carbon atoms (B). We checked also that the hollow of the hexagonal ring of the first layer did not present any significant adsorption in agreement with previous studies [5,6]. The atomic coverage effect has been studied considering

the adsorption of one O atom over three different unit cells: 1x1, 2x2 and 3x3, namely 50 %, 12.5 % and 5.5 % respect the C atoms (i.e., T1 and T2 sites). These coverages would be doubled taking into account only the most stable adsorption sites (i.e., true minima), which correspond to the bridges (i.e., B sites); when an O is over a bridge site the closest free bridges become unavailable for another O adsorption because every C atom can make only four bonds. We will indicate this coverage throughout the text giving both values (i.e., % respect C or top sites / % respect bridge sites).

Table 2 presents the results for the atomic adsorption on T1, T2 and B sites for several oxygen coverages for a two-layer rigid slab. There are negligible differences with respect to the very small adsorption energies or the O-C distances for T1 and T2 sites. The bridge site is the most stable one for all coverages. The analysis of its harmonic vibrational frequencies shown in table 1 reveals that is a true minimum (i.e., all positive frequencies), and this is more stable for high O coverages, where O images are much closer (e.g., the minimum $d_{OO} = a = 2.467 \text{ \AA}$ for 50% coverage) and can introduce an extra stabilization, in a similar way as was observed for O/graphene [8].

In all calculations we observe that the singlet state is the most stable state for all sites in agreement with previous studies for O/graphite [4-6]. In general, the present results are quite similar to the extensive study of Incze et al. [5,6] by using GGA/PW91 with ultrasoft Vanderbilt type pseudopotentials, although they obtained larger adsorption energies for bridge site (1.89 and 1.73 eV for 50 and 5.5% O/C coverages, respectively), within the rigid slab approximation.

T1 and T2 stationary points mainly present two imaginary frequencies, which seem to connect with the adsorption bridge minimum and with a diffusion transition state (see below for more details), although the slab relaxation can affect as well the character of these frequencies (e.g., reducing to one imaginary value for T1 site at 12.5/25% coverage).

Table 3 summarizes the effect of slab relaxation in the bridge minimum for several O coverages. This geometry relaxation corresponds to a stretching of C-C bond along with a reduction of both C-O bonds, with also a puckering of the two carbon atoms beneath the adatom. This behavior is in good agreement with a similar DFT study by means of GGA/PW91 with ultrasoft pseudopotentials [4], which shows $d_{O-C} = 1.472 \text{ \AA}$ and $d_{C-C} = 1.500 \text{ \AA}$, compared to the graphite $d_{C-C} = 1.420 \text{ \AA}$ for a 5.5/11.1 % of coverage. However, a larger adsorption energy (1.91 eV) was calculated in that work. We observe as well that the slab relaxation implies that the adsorption energy tend to be larger for low O coverages (table 3), conversely to the behavior found for rigid slab (table 2). The small changes in E_{ad} (i.e., $\pm 0.3 \text{ eV}$) produced by coverage and slab relaxation effects seem to be counterbalanced.

The formation of this epoxide-like (COC) ring structure on bridge sites has been observed in theoretical and experimental studies on graphene [9] and graphite [44-46] oxides. Thus, for symmetrical graphene epoxide [9] the calculated values, $d_{O-C} = 1.42-1.44 \text{ \AA}$ and $d_{C-C} = 1.49-1.50 \text{ \AA}$ (1.41 for clean graphite) at high coverages show a similar trend as in the present work for oxygen over graphite. The epoxide groups enhance the wrinkling of carbon sheets (i.e., $z_C = 0.25-0.27 \text{ \AA}$) in agreement with previous Monte Carlo studies on graphite oxide, showing an average root-mean-square deviation of $0.33 \pm 0.04 \text{ \AA}$ [46], although this effect is reinforced by the hydroxyl groups formed also on top C atoms for a high degree of oxidation. The oxidation of graphite increases also its interplanar spacing from 3.39 \AA to $6.91-6.96 \text{ \AA}$ due to the expansion of the layer planes originated by the accommodation of various oxygen species, according to experiments [44-45] and Monte Carlo simulations [46]. In spite of the poor description of vdW interactions with the present DFT approach, hence we have fixed the interlayer distance (d_{12}) in almost all calculations. Nevertheless, we observe this enlargement for the highest coverage (50/100%), where this distance was relaxed.

A Bader charge analysis of the epoxy group shows an important charge transfer between the C atoms of the surface and the adsorbed oxygen (e.g., $q_O = -0.99$, $q_C = +0.41$, $+0.58$ at 50/100%). This arrangement of negatively charged oxygen could avoid the nucleophilic attack on C atoms, explaining the relative chemical stability of the epoxide groups in graphite oxides, as it was earlier suggested [44].

Table 4 summarizes the properties of transition states for O adsorption and diffusion processes over the basal (0001) graphite surface at several coverages for rigid slab approximation. Adsorption process is clearly activated as it was also demonstrated for atomic hydrogen over graphene ($\Delta E^\ddagger \sim 0.14 \text{ eV}$ at low coverages [47]) or graphite ($\Delta E^\ddagger = 0.23 \text{ eV}$ at 12.5/25 % coverage [48]). The main difference is that H is mainly adsorbed on top carbons while O prefers the bridge sites. The energy barrier is larger for high O coverages, although slab relaxation tends to decrease this barrier as we have observed for 12.5/25% coverage calculations (table 4). Usually more exothermic reactions (i.e., atomic adsorption with slab relaxation) show lower energy barriers (i.e., early TS) in agreement with Hammond's Postulate. The slab relaxation modifies mainly the z of both C atoms below the O adatom, but the O-C distances are almost unchanged (table 4).

The analysis of the imaginary frequency in this transition state confirms that principally the perpendicular movement of oxygen respect the surface (i.e., z_O coordinate) corresponds to the adsorption process. This TS has mainly a triplet character due its proximity to the O gas asymptote.

The diffusion of one absorbed O over a bridge to its closest bridge is also an activated process that follows a path roughly shown in Fig. 2, with a TS mainly with a singlet character as in the adsorption minimum. The imaginary frequency involves mostly a parallel movement to the surface as could be expected for this process. The corresponding energy barrier decreases significantly when the coverage is reduced, likewise as for the adsorption process. However, the slab relaxation increases considerably this energy barrier from 0.38 to 0.73 eV at 12.5/25 % (table 4) as could be expected because the adsorption energy of adatom changed from 0.66 to 1.28 eV due to C relaxation in z direction. Therefore, the adatom should diffuse quickly over the graphite surface only at high temperatures, which is also in agreement with previous values derived for O over graphite ($\Delta E^\ddagger \geq 0.36$ eV at 3.12 % [3]) or graphene ($\Delta E^\ddagger = 0.58$ eV at 16.7 % [8]). Moreover, this fact would be consistent with the observed migration of epoxide groups in the basal plane during the graphite oxide formation because they were stabilized by hydrogen bonding or catalyzed by hydrogen transfer reactions between the mobile epoxide oxygen and the neighboring OH groups (not possible in clean graphite interacting with pure O/O₂ species).

We have also studied with the present DFT approach the adsorption of molecular oxygen on the basal surface of graphite. Thus, perpendicular and parallel initial configurations with its center of mass over the different adsorption sites (Fig. 1) were considered, optimizing all degrees of freedom including also the slab relaxation by using a 2x2 unit cell. There were found very low adsorption energies ($E_{\text{ad}} \leq 0.01$ eV) at long distances of the center of mass from the surface ($z_{\text{com}} = 3.70\text{-}3.75$ Å) with O-O bond distances of 1.238 Å, slightly larger compared to the free molecule bond distance of 1.235 Å. These results are quite similar to previous studies that used either a cluster ($E_{\text{ad}} = 0.011$ eV, $z_{\text{com}} = 4.212$ Å, $d_{\text{OO}} = 1.167$ Å compared with 1.166 Å in O₂(g) [7]) or a slab model ($E_{\text{ad}} = 0.039$ eV, $z_{\text{com}} = 3.362$ Å, $d_{\text{OO}} = 1.238$ Å compared with 1.237 Å in O₂(g) [4]) over graphite, which also showed that triplet state was more stable than the singlet one. However, it is clear that is necessary an accurate description of the vdW interactions to describe properly the small experimental physisorption energy (0.12±0.01 eV at 1 ML coverage [12]).

3.3 Recombination reactions of atomic oxygen

We have found that the atomic recombination processes (i.e., ER and LH reactions) over the basal (0001) graphite surface are activated processes although their energy barriers considerably decrease with coverage increment, as can be seen in table 5. The ER transition state corresponds to a perpendicular O-O orientation over the bridge site (Fig. 2), being the imaginary frequency also a

perpendicular movement that gives place to O₂(g). Contrarily, the LH transition state presents a parallel configuration (Fig. 2) with a similar O-O distance as for ER TS (e.g., for a (2x2) unit cell); in this case the imaginary frequency has a mixture of both parallel and perpendicular movements, as could be expected. There is not experimental information to compare with these energy barriers. However, a similar DFT study with H over graphite (0001) surface for a 12.5/25 % coverage shows that at this low coverage the ER energy barrier would be equally very low (≤ 0.05 eV), as could be observed from cross sections vs. incident energy plot of quantum scattering calculations [48] . However, the authors assumed a puckering of the C atom below the adsorbed H on top ($z = 0.36$ Å), which possibly reduces more this ER energy barrier. Conversely, the relaxation of the slab in the present study could increase this energy barrier for O as occurred for the diffusion process (table 4), because O adatom tend to become more stable (table 3) after slab relaxation. This effect could also be expected for LH reaction, although the slab relaxation effect should be checked with additional calculations.

The LH reaction should be much less important than ER (or hot atom) reaction as can be concluded from the large differences in their energy barriers as will be confirmed in the next section. This fact has also been previously found out for these O recombination reactions over β -cristobalite [49].

3.4 A microkinetic model for O/O₂ mixtures over graphite

We propose a first microkinetic model to estimate the overall effect of all studied heterogeneous processes involving different O/O₂ mixtures over a graphite (0001) surface. Six surface elementary processes are included:

Chemisorption (k_1) and desorption (k_{-1}) of atoms:



Langmuir-Hinshelwood reaction (k_2) and dissociative molecular adsorption (k_{-2})



Eley-Rideal reaction (k_3) and another dissociative molecular adsorption channel (k_{-3})



where s indicates a free site on the surface. Non-dissociative molecular adsorption is not taken into account because the almost negligible before-mentioned O_2 physisorption. The O_2 dissociation can produce several final products (e.g., $O_{ad} + O_{ad}$, $O_{(g)} + O_{ad}$,...). For each elementary step, the rate constant can be derived from the standard Transition State Theory [35] by the general equation

$$k(T) = \frac{k_B T}{h} \frac{q_{\ddagger}}{q_r} e^{-\Delta E_0^{\ddagger}/k_B T} \quad (6)$$

where k_B is the Boltzmann constant, T is the temperature (assuming that gas and surface temperatures are equal), h is the Planck constant, q_{\ddagger} is the partition function of the transition state (lacking one degree of freedom), q_r is the partition function of reactants and ΔE_0^{\ddagger} represents the energy barrier for the corresponding process including the zero point vibrational correction. In the case of LH and its reverse rate constants (i.e., $k_2(T)$ and $k_{-2}(T)$) also include the factor $1/[s]_0$, where $[s]_0$ is the initial surface density of free sites (i.e., 1.90×10^{19} bridge sites/m² for the graphite (0001) surface). We have used the DFT data for slab rigid and low coverage calculations (i.e., 12.5/25 % for one adatom processes or 11.1/22.2% for LH reaction) in order to derive the different thermal rate constants. Fig. 3 shows the energetics of the different elementary steps and Fig. 4 the calculated TST rate constants within the 400-2000 K range of temperature. It is evident that there are large differences in rate constants, which will have an important influence on the global kinetics of the system once the concentrations are included.

From the differential equation for adsorbed atomic oxygen ($d[O_{ad}]/dt$) can be developed the expression in terms of the atomic surface coverage (θ_o), which takes the form:

$$\begin{aligned} \frac{d\theta_o}{dt} = & \theta_o^2 \left(\frac{2}{3} k_{-2} [O_2] [s]_0 - 2 \frac{2}{3} k_2 [s]_0 \right) - \theta_o \left((k_1 + k_3) [O] + 2 \frac{2}{3} k_{-2} [O_2] [s]_0 + k_{-3} [O_2] + k_{-1} \right) \\ & + \left(k_1 [O] + \frac{2}{3} k_{-2} [O_2] [s]_0 + k_{-3} [O_2] \right) \end{aligned} \quad (7)$$

where the $2/3$ factor takes into account that only for LH reaction (or its reverse) two adatoms (or two free sites) not in adjacent bridges and separated only with a C-C bond are able to react (e.g., 4 from 6 possibilities in a 2x2 cell). The numerical integration of this differential equation for a constant flux of an O/O_2 mixture impinging over the surface allows to see the time-evolution of θ_o .

It is worth noting that a steady-state (ss) is reached rapidly for different initial conditions (i.e., P_O , P_{O_2} and T) with a final low atomic coverage in all studied cases. Fig. 5 shows θ_O at several temperatures for two representative partial pressures although another combinations were also explored. Thus, very low values of a final steady-state atomic surface coverage ($< 10^{-3}$) are observed between 300 and 1000 K for both mixtures, with larger values for the higher O partial pressure as could be predictable. This chemisorption of atomic oxygen on the (0001) graphite surface has been also revealed experimentally [16], with a low level of adsorption on the basal surface, mainly enhanced by the concentration of defect sites [17]. Moreover, these low final θ_O values support as well our use of DFT data for low coverage in the calculated rate constants.

The shape of θ_O as a function of the temperature shows a maximum at different temperatures (i.e., 400 and 500 K), which depends basically on the initial P_O value as could be expected due to at high temperatures the desorption becomes the most important process.

We have also estimated the atomic oxygen recombination coefficient γ_O from the following equation,

$$\gamma_O = \frac{k_1[O](1-\theta_{O(ss)})[s]_O + k_3[O]\theta_{O(ss)}[s]_O - k_{-1}\theta_{O(ss)}[s]_O}{Z_O} \quad (8)$$

which includes only the process that directly involve atomic oxygen, namely adsorption, ER and desorption, once achieved the steady-state ($\theta_{O(ss)}$), and where Z_O is the number of O collisions per unit area and unit time with a planar surface (Hertz-Knudsen relation),

$$Z_O = [O] \sqrt{\frac{k_B T}{2\pi m_O}} \quad (9)$$

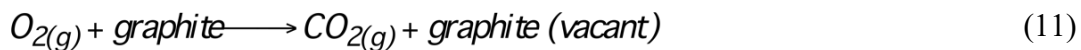
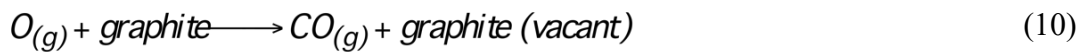
where m_O is the atomic oxygen mass.

The γ_O coefficient shown in Fig. 5 almost mimics the shape of the θ_O plot. An analysis of its three contributions establishes clearly that at low temperatures adsorption and ER reaction are the most important processes with similar contributions, while at high temperatures this occurs for adsorption and desorption processes although in this case their rates are counterbalanced (i.e., $r_1 = r_{-1}$), hence that γ_O finally decreases as a consequence of the lower $\theta_{O(ss)}$ values. Although the final steady-state coverage depends as well on LH process (Eq. 7), in the present case its contribution is unimportant due to its low rate constants.

The comparison of the $\gamma_{\text{O}}(T)$ shape over graphite respect to other materials (e.g., metals [50], alumina [51], silica [52],..) is similar but with much minor values. Moreover, the γ_{O} decline is produced at much lower temperatures for graphite, possibly as a consequence of its lower adsorption energies. The introduction of new rate constants based on DFT data with slab relaxation and /or higher coverages do not produce significant changes respect the present results as we have checked with some additional calculations.

The presence of molecular oxygen (i.e., $P_{\text{O}_2} \neq 0$) in the initial flux is negligible within the studied temperature range (300-1000 K) for both γ_{O} and θ_{O} . This is supported by the large energy barriers (Fig. 3) associated to the two dissociative molecular processes (i.e., very small k_{-2} and k_{-3}) included into the microkinetic model.

The very low γ_{O} coefficients and the large melting point of graphite (4800 ± 100 K at a pressure of 10-100 MPa [53]) could seemingly indicate that C-based materials would be a good proposal to be used as TPS for atmospheres containing oxygen. Nevertheless, the oxidative etching of graphite, forming $\text{CO}(g)$ and also $\text{CO}_2(g)$, can degrade this material and would prevent its use even at moderate temperatures. In fact, several experimental studies [17,54,55] have shown that O_2 (or O) oxidation can produce finally $\text{CO}(g)$ in spite of this endothermic process has a high energy barrier around 3-4 eV, arising from the adsorbed O. Although this carbon etching is mainly enhanced by defect sites, at temperatures larger than 1148 K also occurs in basal plane carbon atoms [54]; HOPG samples at 298-493 K exposed to pulsed hyperthermal beams containing atomic and molecular oxygen yield an important and spatially anisotropic etching [19]. For this reason we have only made calculations with the proposed microkinetic model up to 1000 K. Therefore, at higher temperatures these etching processes and another surface processes should be included, as for instance:



In spite of this kind of microkinetic models are frequently used to simulate the heterogeneous chemical kinetics of dissociate airflow impinging different kind of surfaces [56, 57], with good agreement in comparison to available experimental data (e.g., total heat flux to the surface, γ coefficients,..), more sophisticated Monte Carlo simulations (e.g., N over silica [50], H over graphite [58]) can also be performed including for instance different types of Eley-Rideal mechanisms or the coverage effect through the time evolution of the system.

4 Conclusions

In this work we have made a periodic DFT study (GGA/RPBE) on the main elementary heterogeneous processes involving atomic and molecular oxygen over a graphite (0001) surface to present a comprehensive view on its reactivity.

DFT calculations on bulk graphite (e.g., lattice parameters, cohesive energy, isotropic bulk modulus,..) and on O₂ molecule show a quite good agreement with experimental data. The use of one or two layers for the slab model of graphite in the study of the elementary processes seem to be equivalent. The introduction of slab relaxation is relevant for both adsorption energies and the different energy barriers.

Atomic adsorption is an activated process, whose energy barrier decreases for lower coverages and under slab relaxation. The O adsorption is mainly produced on C-C bridge sites with a considerable puckering of these carbons. This epoxide-like (COC) ring structure has also been observed in earlier theoretical and experimental studies on graphene and graphite oxides.

Atomic diffusion between bridge sites is also an activated process, with lower energy barriers at low coverages but with higher values when slab relaxation is allowed, due to the larger O_{ad} stabilization.

Atomic recombination processes via ER and LH mechanisms are also activated processes although their energy barriers decrease with coverage increment, especially for ER reaction, which will dominate the atomic recombination reaction from low to high temperatures.

We have proposed a microkinetic model with 6 elementary steps, which confirms the very small contribution of the LH process and predicts a very low atomic coverage (< 0.5 %), which along with the small rate constants originates very low atomic recombination coefficients (γ_O). At low temperatures adsorption and ER reaction are the most important processes with similar contributions, while at high temperatures this occurs for adsorption and desorption processes although in this case their rates are compensated. The increase of O partial pressure augments γ_O while the presence of molecular oxygen has no consequences. Temperature raise enhances γ_O values until reaching a temperature where the desorption becomes very important, hence diminishing γ_O .

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Table 1 Calculated and experimental lattice parameters, interatomic distances, cohesive energy, isotropic bulk modulus and its pressure derivative for graphite compound

Method	a=b (Å)	c (Å)	d _{C-C} (Å)	E _{coh} (eV/atom) ^a	B _{iso} (GPa) ^a	B' _{iso} ^a
PW91	2.465	7.698	1.423	7.856	275.4	4.04
PBE	2.467	7.816	1.425	7.847	277.4	3.69
RPBE	2.467	8.022	1.425	7.516	270.3	4.29
LDA/CA ^b	2.441	6.64	-	8.903	-	-
GGA/PW91 ^b	2.461	~ 9.0	-	7.865	-	-
Experiment	2.456 ^c	6.696 ^c	1.418 ^c	7.371±0.005 ^d	318±11 (0 K) ^e 286±11 (300 K) ^e	13.6 (295 K) ^f

^a E_{coh}, B_{iso} and B'_{iso} were calculated using the experimental *c* lattice value

^b LDA/Ceperley-Alder and GGA/Perdew-Wang 91 previous calculations with ultrasoft pseudopotentials [37]

^c Experimental values [36]

^d Experimental value [38] derived from Δ_fH^o(0 K) for the process: C(*graphite*) → C(*g,ideal*)

^e Experimental values [40,41] obtained from elastic constants (C_{ij}) through the formula:

$$, [42]$$

^f Experimental value [40] obtained from the pressure derivative of the previous equation

Table 2 Calculated properties for O adsorption over a basal (0001) graphite surface, without slab relaxation ^a

coverage (%) ^b	site ^c	E _{ad} (eV)	z _O (Å)	d _{O-C} (Å)	ν _i (cm ⁻¹) ^d		
					⊥		
50/100	T1	-0.816	1.544	1.544	574.5	367.2i	374.2i
	T2	-0.811	1.509	1.509	571.0	407.6i	410.5i
	B	0.881	1.251	1.440	822.6	610.6	379.7
12.5/25	T1	0.281	1.556	1.556	542.7	89.0i	95.1i
	T2	0.308	1.554	1.554	583.2	196.1i	201.2i
	B	0.660	1.385	1.557	548.7	325.8	315.2
5.5/11.1	T1	0.0215	1.589	1.589	489.7	142.0	133.1
	T2	0.0673	1.584	1.584	526.8	151.7i	170.5i
	B	0.541	1.384	1.557	538.3	389.4	350.0

^a The slab geometry (two C layers) is fixed at its optimum geometry (d_{C-C} = 1.425 Å) derived in absence of O but with the interlayer distance (d_{l2}) fixed to its experimental value (3.347 Å)

^b The coverage is calculated respect the top sites (O/C %) or the bridge sites (O/bridge %) to facilitate the comparison with previous studies

^c In T1 and T2 sites only the z_O variable is optimized

^d Harmonic vibrational frequencies of the atomic adsorbate with respect to the rigid substrate. The first one corresponds to a perpendicular vibration and the other to parallel vibrations to the graphite surface

Table 3 Calculated properties for O adsorption over a bridge site of a (0001) graphite surface, with some slab relaxation ^a

coverage (%)	E_{ad} (eV)	z_O (Å) ^b	z_C (Å) ^b	d_{O-C} (Å)	d_{C-C} (Å)	ν_i (cm ⁻¹) ^d	
						\perp	\parallel
50/100	0.945	1.254	--- ^c	1.437	1.432	830.7	617.8 400.7
12.5/25	1.283	1.532	0.246	1.482	1.472	652.4	411.3 337.2
5.5/11.1	1.255	1.547	0.267	1.478	1.479	655.2	438.1 337.0

^a The carbon atoms directly bound to oxygen adatom on B site are allowed to relax in all directions

^b $z = 0$ at the first layer formed by the C atoms without including the carbons underneath the O, which are at d_{C-C} separation

^c For the highest coverage (50/100%) the C relaxation implies that all the first layer is shifted upwards (i.e., d_{12} increases to 3.957 Å). For another coverages d_{12} is kept fixed to its experimental value (3.347 Å)

^d Harmonic vibrational frequencies of the atomic adsorbate with respect to the rigid substrate. The first one corresponds to a perpendicular vibration and the other to parallel vibrations to the graphite surface

Table 4 Calculated properties of the transition states for O adsorption and diffusion processes over the basal (0001) graphite surface ^a.

process and coverage ^b	ΔE^\ddagger (eV) ^c	z_O (Å) ^d	d_{O-C} (Å) ^d	ν_i (cm ⁻¹) ^e		
				\perp	\parallel	
$O_g + s \rightarrow O_{ad}$ (adsorption)						
50/100 %	0.67 (0.69)	1.755	1.878, 1.910	535.4i	220.2	123.4
12.5/25 %	0.31 (0.32)	1.874	1.940, 2.090	734.1i	103.8	47.5
	0.19 (0.13) ^f	2.060	1.863, 1.918	112.1i	266.7	171.1
5.5/11.0 %	0.28 ^g	1.848	1.981, 1981	-		
$O_{ad} + s' \rightarrow O_{ad'} + s$ (diffusion)						
50/100 %	1.43 (1.49)	1.425	1.955	675.1	611.7i	306.4
12.5/25 %	0.38 (0.42)	1.553	1.555	549.7	188.6i	113.0
	0.73 (0.70) ^f	1.718	1.421	709.6	157.3	101.7i
5.5/11.1 %	0.47 (0.51)	1.585	1.588	519.9	169.8	97.8i

^a The slab geometry (two C layers) is fixed at its optimum geometry ($d_{C-C} = 1.425$ Å) derived in absence of O but with the interlayer distance (d_{12}) fixed to its experimental value (3.347 Å)

^b s or s' correspond to C-C bridge sites

^c Energy barriers respect reactants (including zero point energy between parentheses)

^d The transition state for adsorption is practically over the C-C bridge site and for diffusion is between two non-adjacent C atoms (see Fig. 1)

^e Harmonic vibrational frequencies of the atomic adsorbate with respect to the rigid substrate

^f In this case the carbon atoms directly bound to oxygen adatom are allowed to relax in all directions (i.e., $z_C = 0.314$ and 0.297 Å for adsorption and diffusion TSs, respectively)

^g This TS was derived approximately from the crossing between the singlet and triplet curves

Table 5 Calculated properties of the transition states for Eley-Rideal (ER) and Langmuir-Hinshelwood (LH) processes involving O atoms over the basal (0001) graphite surface ^a.

process and coverage ^b	ΔE^\ddagger (eV) ^c	z_{O} (Å) ^d	$d_{\text{O-C}}$ (Å) $d_{\text{a}}, d_{\text{b}}$ ^d	$d_{\text{O-O}}$ (Å)	ν_i (cm ⁻¹) ^e						
					\perp	\parallel					
$\text{O}_{\text{g}} + \text{O}_{\text{ad}} \rightarrow \text{O}_{2\text{g}} + \text{s}$ (ER reaction)											
50/100 %	1.11 (1.06)	1.525, 3.235	1.685, 1.682	1.711	962.4i	246.7	339.7	152.8	124.2	63.5	
12.5/25 %	0.10 (0.076)	1.499, 3.492	1.647, 1.672	2.024	527.9i	209.5	301.8	268.4	87.7i	33.9	
$\text{O}_{\text{ad}} + \text{O}_{\text{ad}} \rightarrow \text{O}_{2\text{g}} + 2\text{s}$ (LH reaction)											
25/50 %	1.91 (1.87)	1.569, 1.570	1.609, 1.610	1.736	611.6i	496.8	397.4	330.0	256.2	196.0	
11.1/22.2 %	1.28 ^f	1.600, 1.600	1.625, 1.622	1.774							

^a The slab geometry (two C layers) is fixed at its optimum geometry ($d_{\text{C-C}} = 1.425$ Å) derived in absence of O but with the interlayer distance (d_{12}) fixed to its experimental value (3.347 Å)

^b s or s' correspond to C-C bridge sites. For LH reaction coverages are necessarily doubled respect ER or adsorption processes, when using the same unit cell

^c Energy barriers respect reactants (including zero point energy between parentheses)

^d The transition state geometries for ER and LH reactions are depicted in Fig. 2. <OCCO dihedral is 24.7° at 25/50% and 16.8° at 11.1/22.2% for LH TS

^e Harmonic vibrational frequencies of the atomic adsorbate with respect to the rigid substrate. Approximately, the two first correspond to perpendicular and the other to parallel vibrations respect the graphite surface for the ER reaction. In the case of LH reaction the imaginary frequency shows as mixture of parallel and perpendicular movements

^f This TS was derived approximately from some grids of points

Figure 1

Top view of the graphite (0001) slab two-layer model with the different adsorption sites: bridge (B), on top a C with also a C below (T1) and on top a C without a C below (T2). The atoms of the second layer are plotted a bit larger and with light color to be distinguished from first layer atoms. The transition state for O diffusion between two bridge adsorption sites is also shown. The solid line shows the surface 1x1 unit cell

Figure 2

Geometries corresponding to transition states for: a) ER reaction and b) LH reaction, labeling the different interatomic distances.

Figure 3

Energy diagram for several O heterogeneous elementary processes over a graphite (0001) surface for a 12.5/25 % coverage (11.1/22.2% for LH reaction). Values between parentheses give the energy barriers without ZPE respect the closest reactants. O₂ dissociation energy can change in approximately in ± 0.1 eV due to a small size consistency problem in the asymptotes (i.e., O(³P) + O(³P) + slab calculated as supermolecule or as fragments addition)

Figure 4

Calculated TST thermal rate constants for the different heterogeneous processes involved in the proposed microkinetic model, based on DFT data for a 12.5/25 % coverage (11.1/22.2% for LH reaction). Only k_i with same units (shown inside the plot) could be directly compared. Points are connected with a line to guide the view

Figure 5

Atomic surface coverage and γ_O coefficient in front the temperature for two O/O₂ initial mixtures: circles (100, 100 Pa) and squares (5000, 0 Pa)

Fig.1:

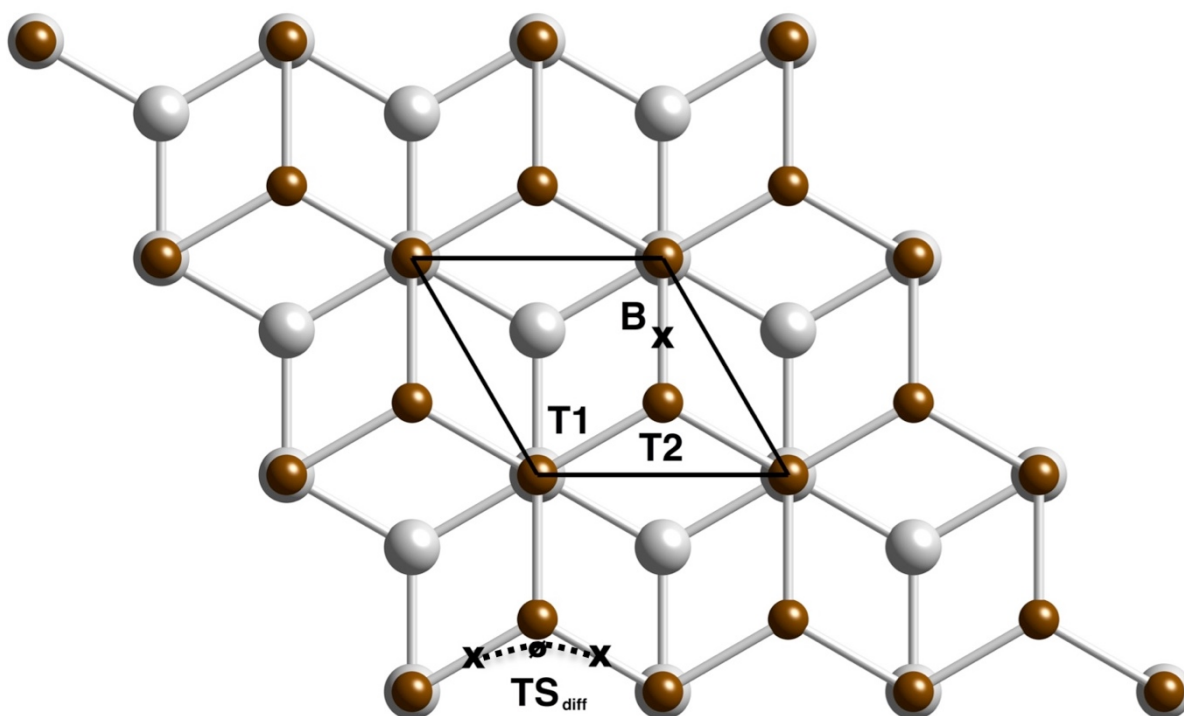


Fig.2:

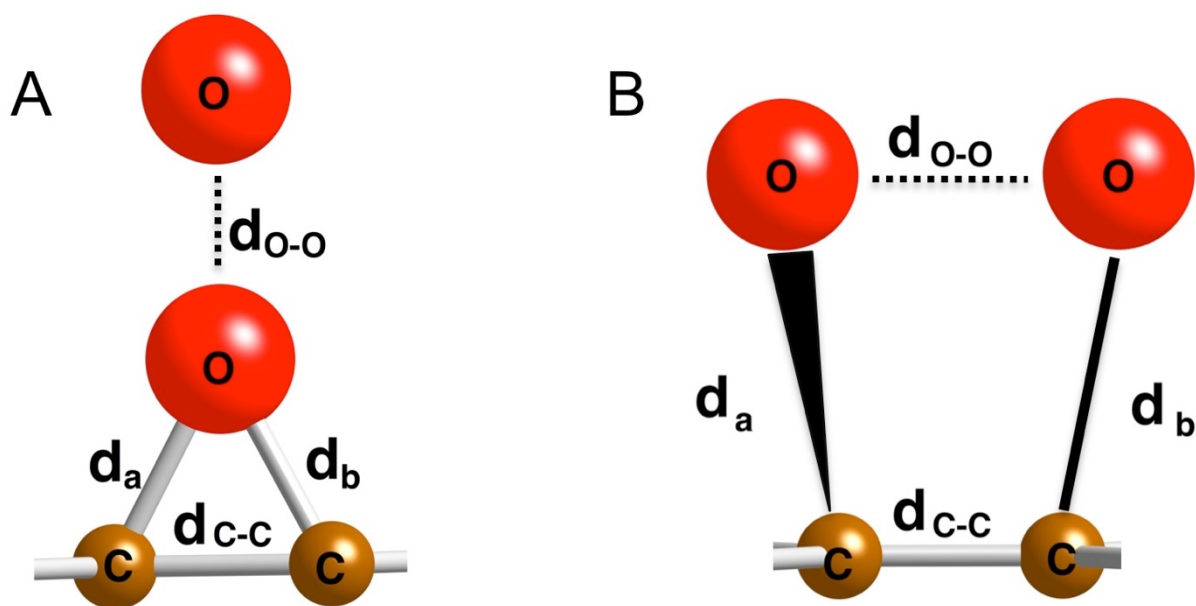


Fig.3:

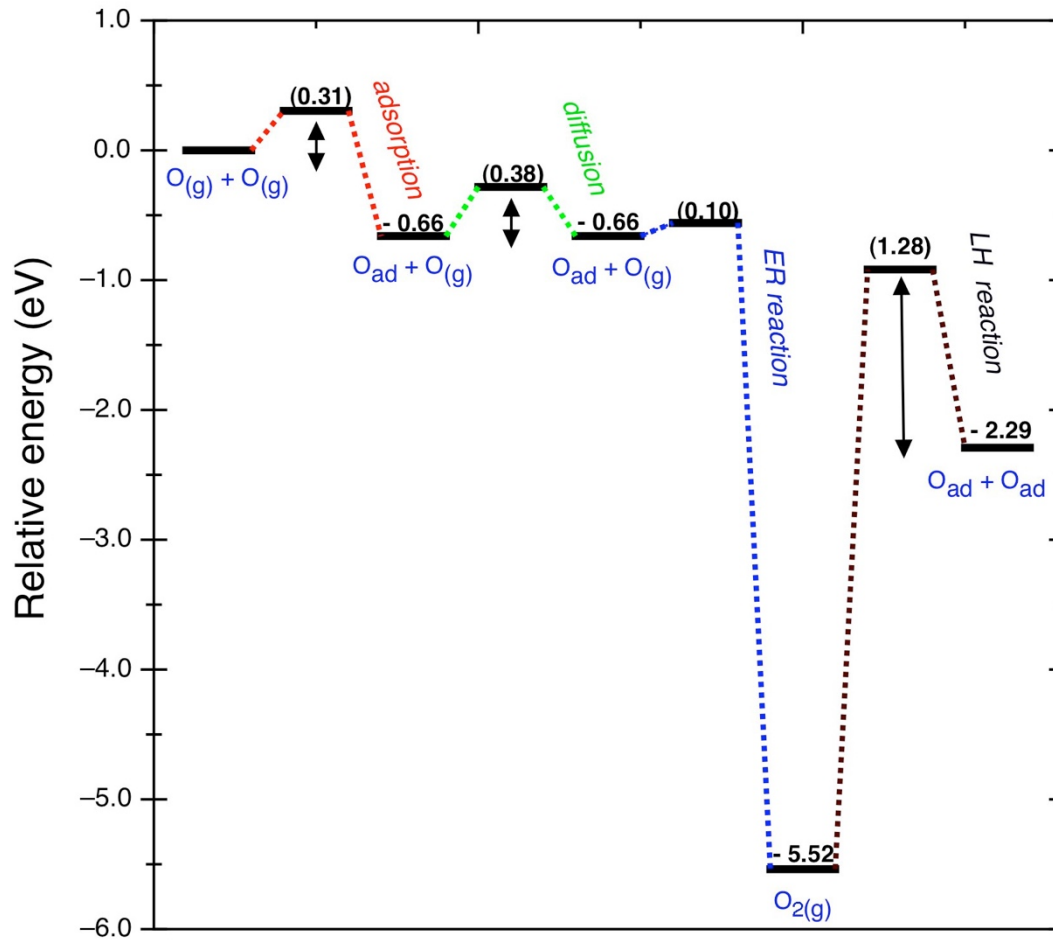


Fig. 4:

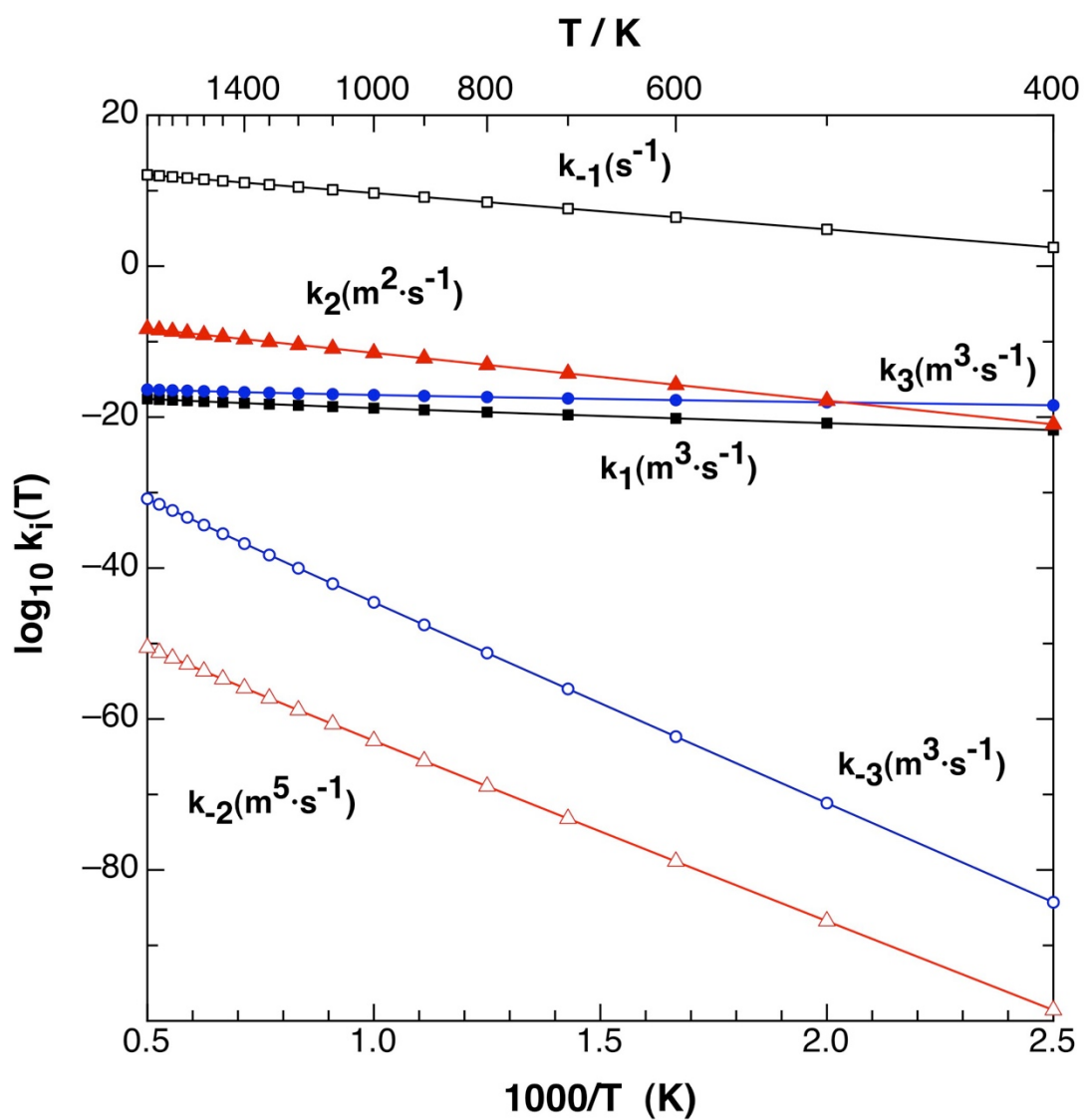


Fig. 5:

